DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

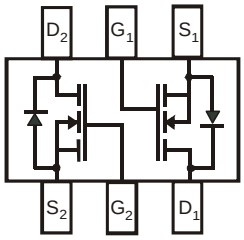
Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram (Note 3)
- Terminals: Finish - Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.003 grams (approximate)

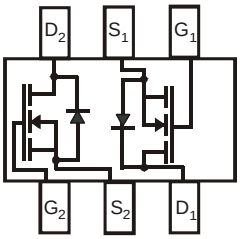
SOT563



Top View



2N7002VC
(ASK Marking Code)



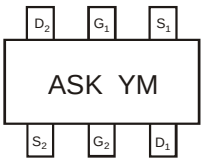
2N7002VAC
(AYK Marking Code)

Ordering Information (Note 4)

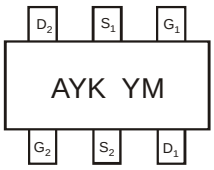
Part Number	Case	Packaging
2N7002VC-7	SOT563	3000/Tape & Reel
2N7002VAC-7	SOT563	3000/Tape & Reel

Notes:
1. No purposefully added Lead.
2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.
3. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



ASK = 2N7002VC Product Type Marking Code (See Note 1)
YM = Date Code Marking
Y = Year ex: R = 2004
M = Month ex: 9 = September



AYK = 2N7002VAC Product Type Marking Code (See Note 1)
YM = Date Code Marking
Y = Year ex: R = 2004
M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	R	S	T	U	V	W	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V_{DSS}	60	V
Drain-Gate Voltage $R_{GS} \leq 1.0M\Omega$		V_{DGR}	60	V
Gate-Source Voltage (Note 5)	Continuous Pulsed	V_{GSS}	±20 ±40	V
Drain Current (Note 5)	Continuous	I_D	280	mA
Drain Current (Note 5)	Pulsed	I_{DM}	1.5	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation	P_D	150	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage		BV_{DSS}	60	70	—	V	V_{GS} = 0V, I_D = 10μA
Zero Gate Voltage Drain Current	@ T_C = 25°C @ T_C = 125°C	I_{DSS}	—	—	1.0 500	μA	V_{DS} = 60V, V_{GS} = 0V
Gate-Body Leakage		I_{GSS}	—	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTIC (Note 6)							
Gate Threshold Voltage		$V_{GS(th)}$	1.0	—	2.5	V	V_{DS} = V_{GS}, I_D = 250μA
Static Drain-Source On-Resistance		$R_{DS\ (ON)}$	— —	— —	7.5 13.5	Ω	V_{GS} = 5V, I_D = 0.05A, V_{GS} = 10V, I_D = 0.5A, T_j = 125°C
On-State Drain Current		$I_{D(ON)}$	0.5	1.0	—	A	V_{GS} = 10V, V_{DS} = 7.5V
Forward Transconductance		g_{FS}	80	—	—	mS	V_{DS} = 10V, I_D = 0.2A
DYNAMIC CHARACTERISTICS							
Input Capacitance		C_{iss}	—	—	50	pF	V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance		C_{oss}	—	—	25	pF	
Reverse Transfer Capacitance		C_{rss}	—	—	5.0	pF	
SWITCHING CHARACTERISTICS							
Turn-On Delay Time		$t_{D(ON)}$	—	—	20	ns	V_{DD} = 30V, I_D = 0.2A, R_L = 150Ω,
Turn-Off Delay Time		$t_{D(OFF)}$	—	—	20	ns	V_{GEN} = 10V, R_{GEN} = 25Ω

Notes: 5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com.
6. Short duration pulse test used to minimize self-heating effect.

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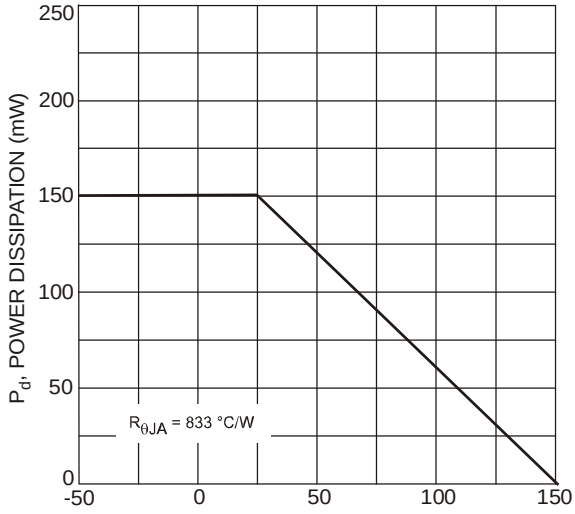
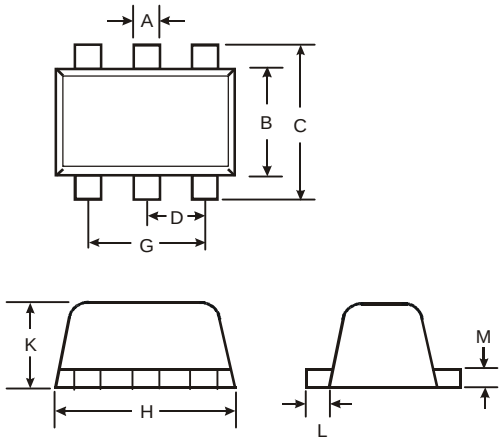


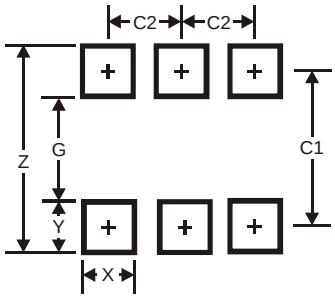
Fig. 1, Derating Curve - Total

Package Outline Dimensions



SOT563			
Dim	**Min**	**Max**	**Typ**
A	0.15	0.30	0.20
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	-	-	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.55	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.2
G	1.2
X	0.375
Y	0.5
C1	1.7
C2	0.5

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